

Product specification

1999 Apr 05



20-bit bus switch with precharged outputs and Schottky undershoot protection for live insertion

CBT6820

FEATURES

- TTL compatible inputs and outputs
- 5Ω switch connection between two port A and port B
- Thin shrink small outline (TSSOP)
- Undershoot protection included to prevent shoot through level changes
- Bias voltage pre-charges the outputs to minimize signal distortion during live insertion

DESCRIPTION

The CBT6820 provides twenty bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows bi-directional connections to be made while adding near-zero propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The device is organized as two 10-bit switch with individual enable (OE) input. When OE is low, the switch is on and port A is connected to port B. When OE is high, the switch between port A and port B is open and the B port is precharged to BIASV through the equivalent of a 10-k Ω resistor.

Special clamp circuitry and Schottky diode clamps to ground are used to prevent an under voltage on the A side (Vin < GND) from causing the B side precharge voltage to drop below the "1" state.

PIN CONFIGURATION

		-	
BIAS	V 1	48	1 0E
14	1 2	47	2 0E
14	v2 3	46	1B1
14	4	45	1B2
14	4 5	44	1B3
14	v2 6	43	1B4
14	.6 7	42	1B5
GN	D 8	41	GND
14		40	1B6
	.8 10	39	1B7
14	.9 11	38	1B8
	0 12	37	1B9
	1 13	36	1B10
	14	35	2B1
	C 15	34	2B2
	.3 16	33	2B3
	D 17	32	GND
	4 18	31	2B4
	19	30	2B5
	16 20	29	2B6
	17 21	28	2B7
	.8 22	27	2B8
	N9 23	26	2B9
2A1	0 24	25	2B10
			SA00520

QUICK REFERENCE DATA

SYMB	OL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} /t _P	ΉL	Propagation delay An to Bn or Bn to An	C _L = 50 pF, V _{CC} = 5 V	0.25	ns
C _{IN}		Input capacitance		4.5	pF
C _{I/O}		Input/output capacitance	Outputs disabled; $V_0 = 0 V \text{ or } V_{CC}$	9.5	pF

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic TSSOP Type II	–40°C to +85°C	CBT6820 DGG	CBT6820 DGG	SOT362-1

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PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	BIASV	Bias voltage
2, 3, 4, 5, 6, 7, 9, 10, 11,12	1A1–1A10	Port 1A1 to Port 1A10
8, 17, 32, 41	GND	Ground (V)
13, 14, 16, 18, 19, 20, 21, 22, 23, 24	2A1–2A10	Port 2A1 to Port 2A10
15	V _{CC}	Positive supply voltage
35, 34, 33, 31, 30, 29, 28, 27, 26, 25	2B1–2B10	Port 2B1 to Port 2B10
46, 45, 44, 43, 42, 40, 39, 38, 37, 36	1B1–1B10	Port 1B1 to Port 1B10
48, 47	1 <u>0E</u> , 2 <u>0E</u>	Switch enables

FUNCTION TABLE

ŌĒ	STATE
L	A Port = B Port
н	A Port = Z
Н	B Port = BIASV

H = High voltage level

L = Low voltage level

Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC clamp diode current	V ₁ < 0	-50	mA
VI	DC input voltage ¹		-0.5 to +7.0	V
I _{SW}	DC continuous channel current	$V_{O} = 0$ to V_{CC}	±128	mA
V _{BIASV}	DC bias voltage		-0.5 to +7.0	V
T _{stg}	Storage temperature range		-65 to 150	°C
øJA	Plastic thin shrink small outline package (TSSOP)		104	°C/W

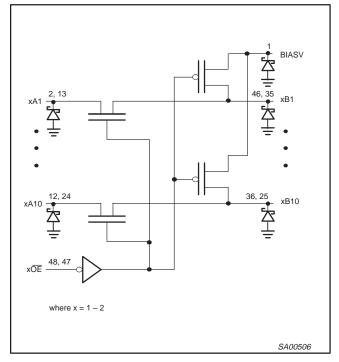
NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STMBUL	PARAMETER	Min	Max	UNIT
V _{CC}	DC supply voltage	4.0	5.5	V
BIASV	DC supply voltage	1.3	V _{CC}	V
V _{IH}	High-level input voltage (control pin)	2.0		V
V _{IL}	Low-level Input voltage (control pin)		0.8	V
T _{amb}	Operating free-air temperature range	-40	+85	°C

LOGIC SYMBOL



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DC ELECTRICAL CHARACTERISTICS

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	T _{amb} = −40°C to +85°C			UNIT
			Min	Typ ¹	Max	1
V _{IK}	Input clamp voltage	V _{CC} = 4.5V; I _I = -18mA			-1.2	V
l	Input leakage current (control pin)	V _{CC} = 5.5V; V _I = GND or 5.5V			±5	μΑ
Ι _Ο	Output bias current (B pins)	V_{CC} = 4.5V; BiasV = 2.4V; V_O = 0, \overline{OE} = V_{CC}			-0.25	mA
I _{CC}	Quiescent supply current	V_{CC} = 5.5V; I _O = 0, V _I = V _{CC} or GND			2.5	mA
ΔI_{CC}	Control pins ²	V_{CC} = 5.5V, one input at 3.4V, other inputs at V_{CC} or GND			2.5	mA
Cl	Input capacitance per OE pin	$V_{I}=3V \text{ or } 0$		4.5		pF
C _{O(OFF)}	Capacitance per port (OFF-state)	$V_0 = 3V$ or 0; switch off		9.5		pF
		$V_{CC} = 4.5V; V_{I} = 0V; I_{I} = 64mA$		5	7	
r _{on} ³	On-resistance	$V_{CC} = 4.5V; V_{I} = 0V; I_{I} = 30mA$		5	7	Ω
		$V_{CC} = 4.5V; V_I = 2.4V; I_I = -15mA$		10	15	1
V _P	Pass voltage	$V_{IN} = V_{CC} = 4.5V; I_{out} = -100\mu A$	3.4	3.6	3.9	V
I _{USP}	Undershoot static current protection ⁴	$ \begin{array}{l} V_{CC} = 5.0 \text{V}, \ V_{Bias} = V_{CC} \\ I_B = -5 \mu \text{A}, \ V_B \geq 3.0 \text{V} \end{array} $		-10		mA

NOTES:

All typical values are at VCC = 5V, TA = 25 C
This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND
Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

4. Force I_{USP}, measure $V_B \ge 3V$

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AC CHARACTERISTICS FOR V_{CC} = 5.0V ±0.5V RANGE

GND = 0V; $t_r = t_f \le 2.5$ ns; $C_L = 50$ pF.

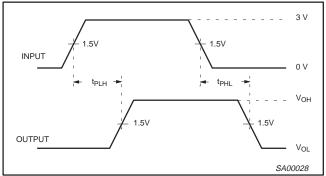
				UNIT		
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = -40 to +85°C			
			MIN	TYP ¹	MAX	1
t _{pd}	Propagation delay; An to Bn; Bn to An ²	1			0.25	ns
t _{PZH}	3-State output enable time OE to An; OE to Bn; BIASV = GND	2	1.3	3.1	5.3	ns
t _{PZL}	3-State output enable time OE to An; OE to Bn; BIASV = 3.0V	2	1.4	2.9	4.6	ns
t _{PHZ}	$\frac{3-\text{State output enable time}}{\text{OE to An; OE to Bn; BIASV} = \text{GND}}$	2	1.7	2.8	4.5	ns
t _{PLZ}	$\frac{3-\text{State output enable time}}{\text{OE to An; OE to Bn; BIASV} = 3.0\text{V}$	2	2.8	4.4	6.6	ns

NOTE:

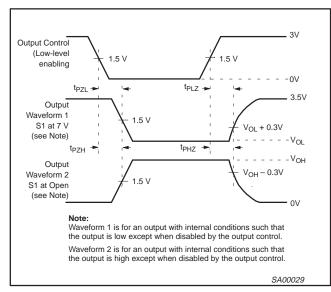
1. All typical values are measured at $T_{amb} = 25^{\circ}C$ and $V_{CC} = 5.0V$ 2. Warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON-state resistance of the switch and a load capacitance of 50pF, when driven by an ideal voltage source (zero output impedance)

AC WAVEFORMS

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$

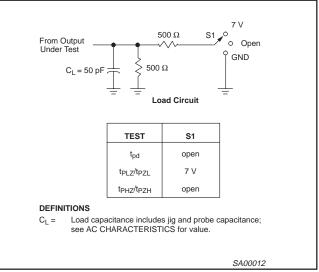


Waveform 1. Waveforms Showing the Input (An) to Output (Bn) **Propagation Delays**



Waveform 2. Waveforms Showing the 3-State Output Enable and **Disable Times**

TEST CIRCUIT AND WAVEFORMS

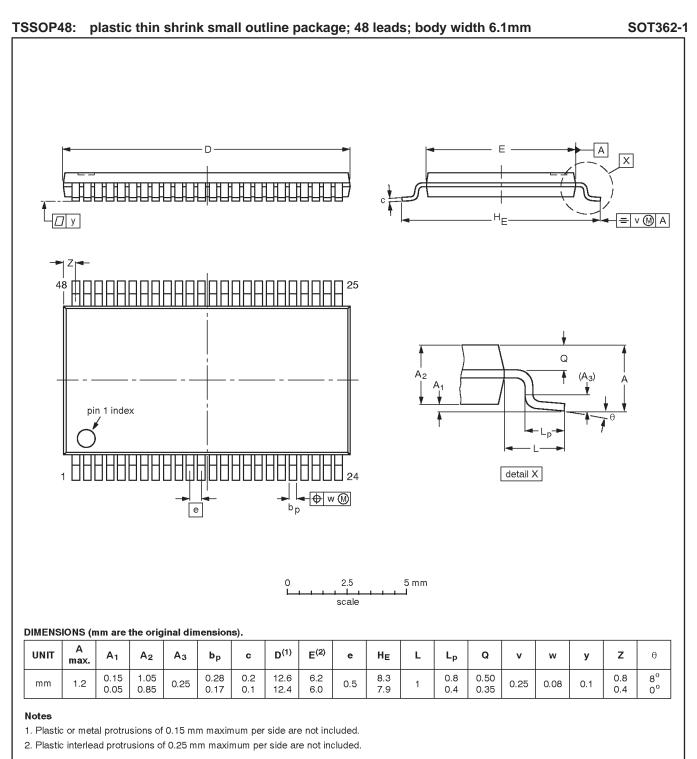


NOTES:

- All input pulses are supplied by generators having the following 1. characteristics: PRR \leq 10MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- 2. The outputs are measured one at a time with one transition per measurement.

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OUTLINE	REFERENCES			EUROPEAN ISSUE DAT			
VERSION	IEC	JEDEC	EIAJ			PROJECTION	1550E DATE
SOT362-1		MO-153ED				0	- 93-02-03- 95-02-10

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DEFINITIONS				
Data Sheet Identification	Product Status	Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
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